RB500V-40 Taiwan Semiconductor

100mA, 45V Low V_F Schottky Barrier Diode

FEATURES

- Designed for mounting on small surface
- Low Capacitance
- Low forward voltage drop
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free

APPLICATIONS

- Adapters
- For switching power supply
- Low stored charge
- Inverter

MECHANICAL DATA

- Case: SOD-323F
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 4.60mg (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
lF	100	mA	
V _{RRM}	45	V	
IFSM	1	А	
V _F at I _F = 10mA	0.45	V	
Тј мах	125	°C	
Package	SOD-323F		
Configuration	Single die		





SOD-323F



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	RB500V-40	UNIT
Marking code on the device			S9	
Peak reverse voltage		V _{RM}	45	V
Reverse voltage		VR	40	V
Forward current		lF	100	mA
Non-repetitive peak forward surge current	t = 8.3ms	I _{FSM}	1	А
Junction temperature range		TJ	-40 to +125	°C
Storage temperature range		T _{STG}	-40 to +125	°C

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient thermal resistance	Reja	500	°C/W





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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Reverse Breakdown Voltage	$I_R = 100 \mu A, T_J = 25^{\circ}C$	V _{BR}	45	-	V
Forward voltage ⁽¹⁾	I _F = 10mA, T _J = 25°C	VF	-	0.45	V
Reverse current @ $V_R^{(2)}$	$V_R = 10V, T_J = 25^{\circ}C$	IR	-	1	μA
Junction capacitance	1MHz, V _R = 10V	CJ	-	6	pF

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

RDERING INFORMATION			
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING	
RB500V-40 RR	SOD-323F	3,000 / 7" Tape & Reel	
RB500V-40 RRG	SOD-323F	3,000 / 7" Tape & Reel	
RB500V-40 R9	SOD-323F	10,000 / 13" Tape & Reel	
RB500V-40 R9G	SOD-323F	10,000 / 13" Tape & Reel	

Notes:

1. "G" means green compound



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

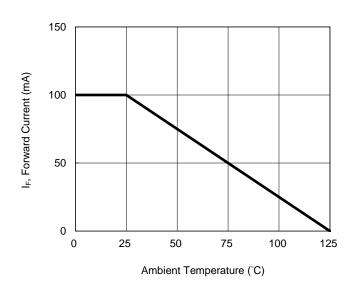


Fig.1 Forward Current Derating Curve

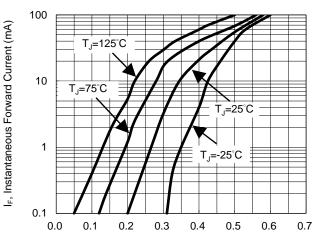
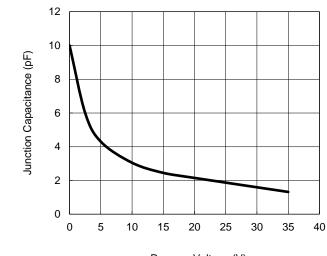


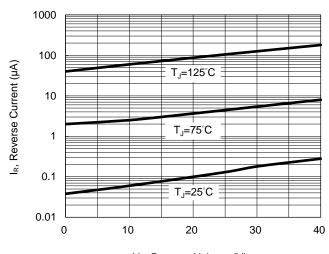
Fig.2 Typical Forward Characteristics

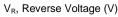
V_F, Instantaneous Forward Voltage (V)

Fig.3 Typical Reverse Characteristics

Fig.4 Typical Junction Capacitance



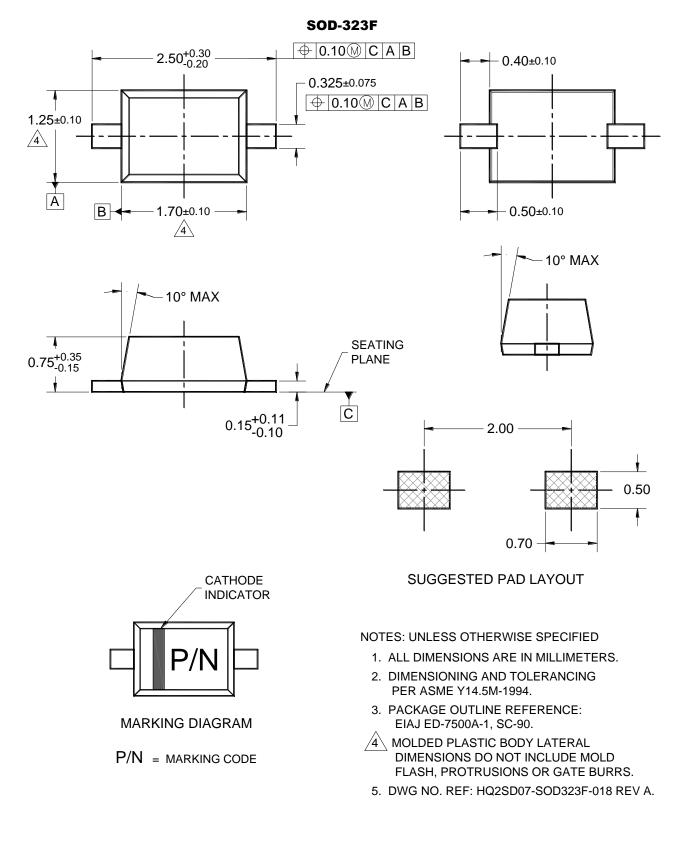




Reverse Voltage (V)



PACKAGE OUTLINE DIMENSIONS





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